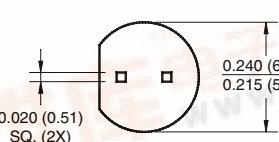
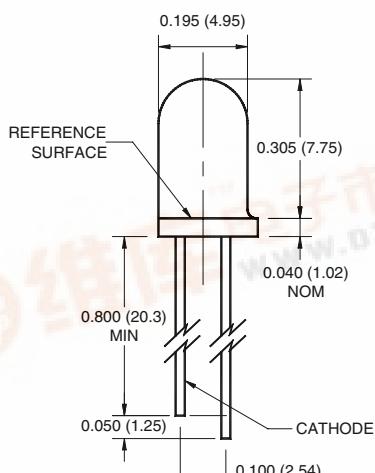
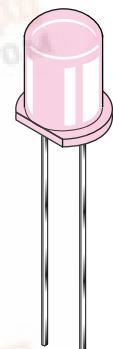
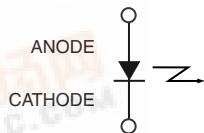


QED121/122/123
**PLASTIC INFRARED
LIGHT EMITTING DIODE**
PACKAGE DIMENSIONS**NOTES:**

- Dimensions for all drawings are in inches (mm).
- Tolerance of $\pm .010$ (.25) on all non-nominal dimensions unless otherwise specified.

FEATURES

- $\lambda = 880$ nm
- Chip material = AlGaAs
- Package type: T-1 3/4 (5mm lens diameter)
- Matched Photosensor: QSD122/123/124
- Narrow Emission Angle, 18°
- High Output Power
- Package material and color: Clear, peach tinted, plastic

**SCHEMATIC****ABSOLUTE MAXIMUM RATINGS** ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Rating	Unit
Operating Temperature	T_{OPR}	-40 to +100	°C
Storage Temperature	T_{STG}	-40 to +100	°C
Soldering Temperature (Iron) ^(2,3,4)	T_{SOL-I}	240 for 5 sec	°C
Soldering Temperature (Flow) ^(2,3)	T_{SOL-F}	260 for 10 sec	°C
Continuous Forward Current	I_F	100	mA
Reverse Voltage	V_R	5	V
Power Dissipation ⁽¹⁾	P_D	200	mW

ELECTRICAL / OPTICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
Peak Emission Wavelength	$I_F = 20$ mA	λ_{PE}	—	880	—	nm
Emission Angle	$I_F = 100$ mA	Θ	—	± 9	—	Deg.
Forward Voltage	$I_F = 100$ mA, $t_p = 20$ ms	V_F	—	—	1.7	V
Reverse Current	$V_R = 5$ V	I_R	—	—	10	μA
Radiant Intensity QED121	$I_F = 100$ mA, $t_p = 20$ ms	I_E	16	—	40	mW/sr
Radiant Intensity QED122	$I_F = 100$ mA, $t_p = 20$ ms	I_E	32	—	100	mW/sr
Radiant Intensity QED123	$I_F = 100$ mA, $t_p = 20$ ms	I_E	50	—	—	mW/sr
Rise Time	$I_F = 100$ mA	t_r	—	800	—	ns
Fall Time	$I_F = 100$ mA	t_f	—	800	—	ns

TYPICAL PERFORMANCE CURVES

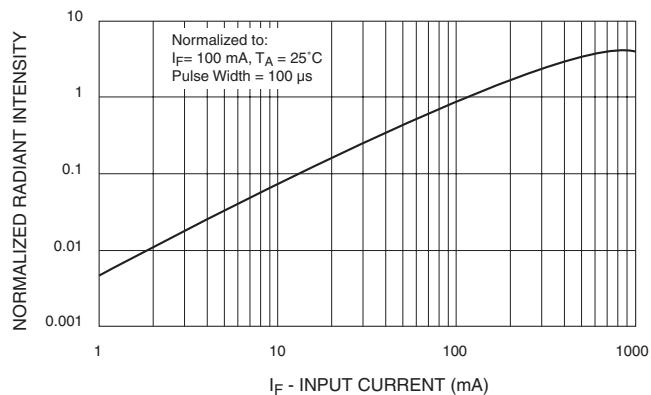


Fig. 1 Normalized Radiant Intensity vs. Input Current

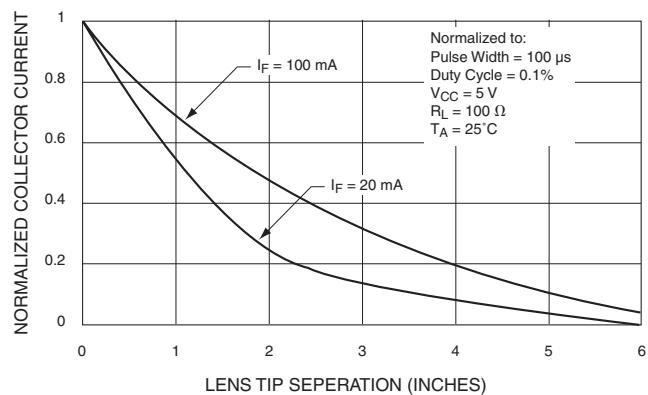


Fig. 2 Coupling Characteristics of QED12X and QSD12X

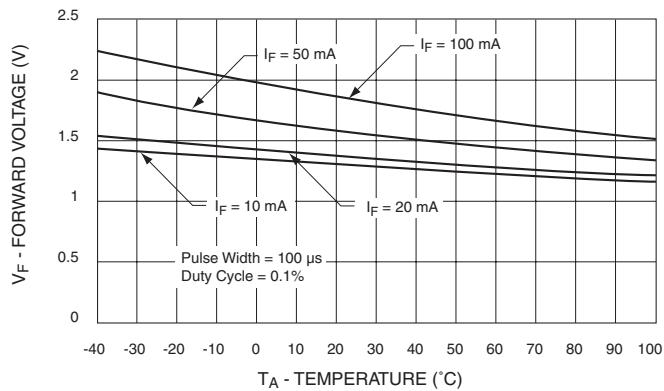


Fig. 3 Forward Voltage vs. Temperature

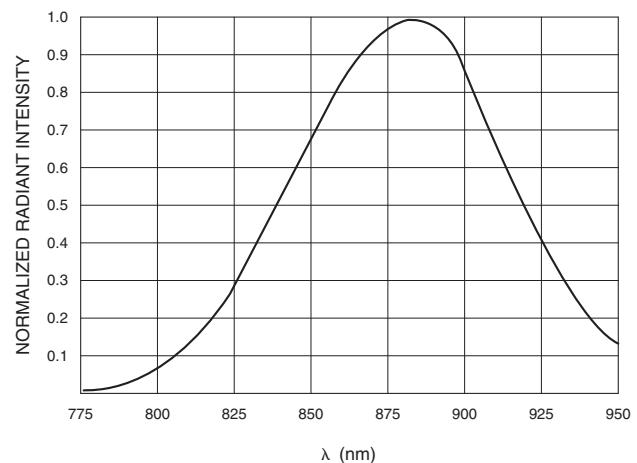
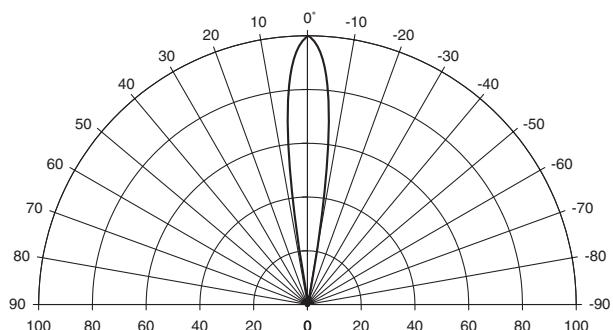


Fig. 4 Normalized Radiant Intensity vs. Wavelength

Fig. 5 Radiation Pattern





QED121/122/123

PLASTIC INFRARED LIGHT EMITTING DIODE

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.